NSN 5961-01-446-4691

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-446-4691 **Inclosure Material:** Metal **Overall Length:** Between 0.130 inches and 0.146 inches Overall Diameter: Between 0.063 inches and 0.067 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc and 75.0 working peak reverse voltage **Current Rating Per Characteristic:** 2.00 amperes forward current, average preset and 200.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 case **Specification Data:** 81349-mil-prf-19500/116 government specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0 Mil-std (military Standard): Mil-prf-19500 spec.